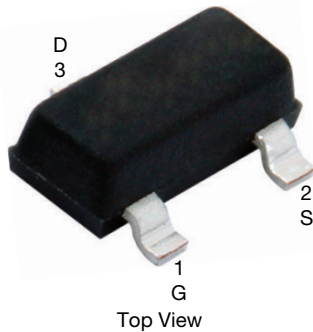


## N-Channel 60 V (D-S) MOSFET

**SOT-23 (TO-236)**

**Marking code: 7K**

PRODUCT SUMMARY	
$V_{DS}$ (V)	60
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = 10$ V	2
$Q_g$ typ. (nC)	0.4
$I_D$ (A)	0.3
Configuration	Single

**FEATURES**

- Low on-resistance:  $2 \Omega$
- Low threshold: 2 V (typ.)
- Low input capacitance: 25 pF
- Fast switching speed: 25 ns
- Low input and output leakage
- TrenchFET® power MOSFET
- 2000 V ESD protection
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**Note**

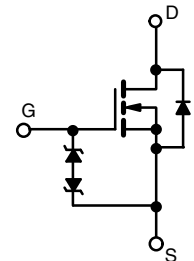
\* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

**BENEFITS**

- Low offset voltage
- Low voltage operation
- Easily driven without buffer
- High speed circuits
- Low error voltage

**APPLICATIONS**

- Direct logic-level interface: TTL/CMOS
- Drivers: relays, solenoids, lamps, hammers, display, memories, transistors, etc.
- Battery operated systems
- Solid state relays



N-Channel MOSFET

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free	2N7002K-T1-E3
Lead (Pb)-free and halogen-free	2N7002K-T1-GE3

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25 \text{ }^\circ\text{C}$ , unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	$V_{DS}$	60	V
Gate-source voltage	$V_{GS}$	$\pm 20$	
Continuous drain current ( $T_J = 150 \text{ }^\circ\text{C}$ ) <sup>b</sup>	$T_A = 25 \text{ }^\circ\text{C}$	0.3	A
	$T_A = 100 \text{ }^\circ\text{C}$	0.19	
Pulsed drain current <sup>a</sup>	$I_{DM}$	0.8	
Power dissipation <sup>b</sup>	$T_A = 25 \text{ }^\circ\text{C}$	0.35	W
	$T_A = 100 \text{ }^\circ\text{C}$	0.14	
Maximum junction-to-ambient <sup>b</sup>	$R_{thJA}$	350	$^\circ\text{C/W}$
Operating junction and storage temperature range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

**Notes**

- Pulse width limited by maximum junction temperature
- Surface mounted on FR4 board



SPECIFICATIONS ( $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP. <sup>a</sup>	MAX.	UNIT
<b>Static</b>						
Drain-source breakdown voltage	$V_{DS}$	$V_{GS} = 0\text{ V}, I_D = 10\text{ }\mu\text{A}$	60	-	-	V
Gate-threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	1	-	2.5	
Gate-body leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$	-	-	$\pm 10$	$\mu\text{A}$
		$V_{DS} = 0\text{ V}, V_{GS} = \pm 15\text{ V}$	-	-	1	
		$V_{DS} = 0\text{ V}, V_{GS} = \pm 10\text{ V}$	-	-	$\pm 150$	nA
		$V_{DS} = 0\text{ V}, V_{GS} = \pm 10\text{ V}, T_J = 85\text{ }^\circ\text{C}$	-	-	$\pm 1000$	
		$V_{DS} = 0\text{ V}, V_{GS} = \pm 5\text{ V}$	-	-	$\pm 100$	
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 60\text{ V}, V_{GS} = 0\text{ V}$	-	-	1	$\mu\text{A}$
		$V_{DS} = 60\text{ V}, V_{GS} = 0\text{ V}, T_J = 125\text{ }^\circ\text{C}$	-	-	500	
On-state drain current <sup>b</sup>	$I_{D(on)}$	$V_{GS} = 10\text{ V}, V_{DS} = 7.5\text{ V}$	800	-	-	mA
		$V_{GS} = 4.5\text{ V}, V_{DS} = 10\text{ V}$	500	-	-	
Drain-source on-resistance <sup>b</sup>	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 500\text{ mA}$	-	-	2	$\Omega$
		$V_{GS} = 4.5\text{ V}, I_D = 200\text{ mA}$	-	-	4	
Forward transconductance <sup>b</sup>	$g_{fs}$	$V_{DS} = 10\text{ V}, I_D = 200\text{ mA}$	100	-	-	mS
Diode forward voltage	$V_{SD}$	$I_S = 200\text{ mA}, V_{GS} = 0\text{ V}$	-	-	1.3	V
<b>Dynamic <sup>a, b</sup></b>						
Total gate charge	$Q_g$	$V_{DS} = 10\text{ V}, V_{GS} = 4.5\text{ V}$ $I_D \cong 250\text{ mA}$	-	0.4	0.6	nC
Input capacitance	$C_{iss}$	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V}$ $f = 1\text{ MHz}$	-	30	-	pF
Output capacitance	$C_{oss}$		-	6	-	
Reverse transfer capacitance	$C_{rss}$		-	2.5	-	
<b>Switching <sup>a, c</sup></b>						
Turn-on time	$t_{d(on)}$	$V_{DD} = 30\text{ V}, R_L = 150\text{ }\Omega$ $I_D \cong 200\text{ mA}, V_{GEN} = 10\text{ V}, R_g = 10\text{ }\Omega$	-	-	25	ns
Turn-off time	$t_{d(off)}$		-	-	35	

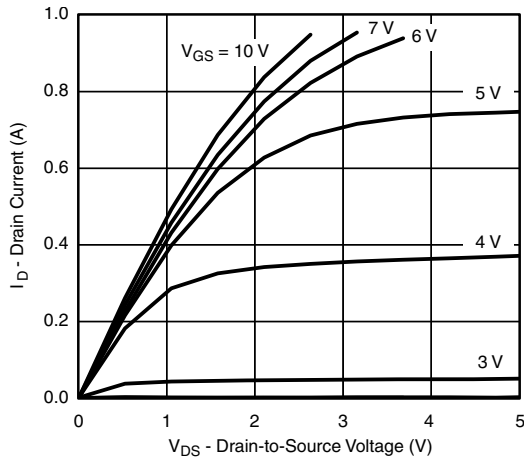
**Notes**

- a. For DESIGN AID ONLY, not subject to production testing  
b. Pulse test: pulse width  $\leq 300\text{ }\mu\text{s}$  duty cycle  $\leq 2\%$   
c. Switching time is essentially independent of operating temperature

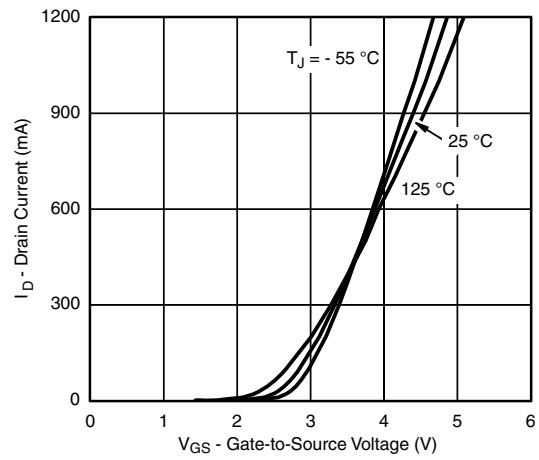
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



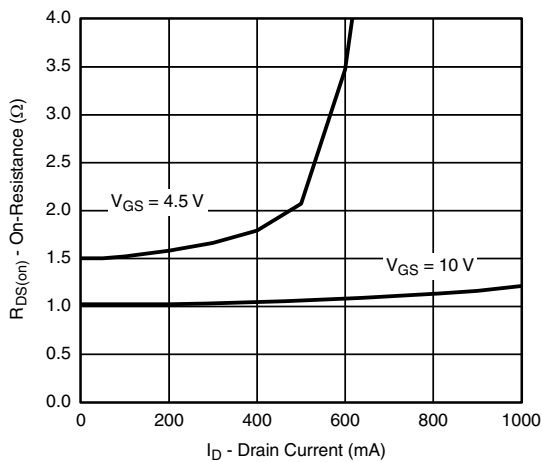
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



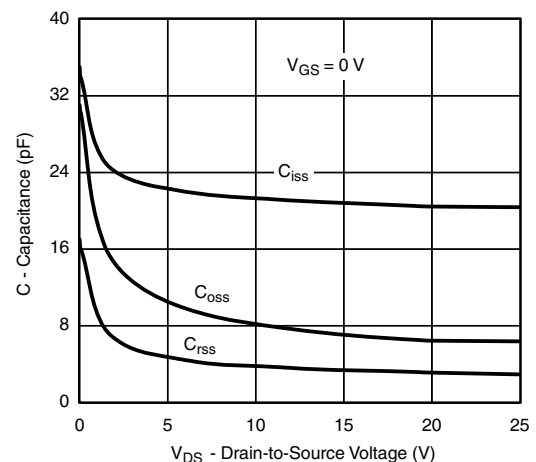
Output Characteristics



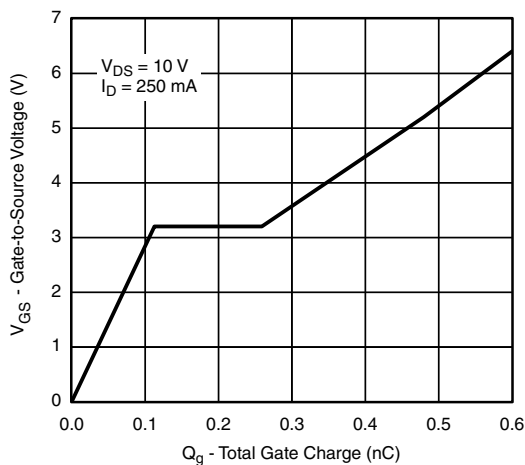
Transfer Characteristics



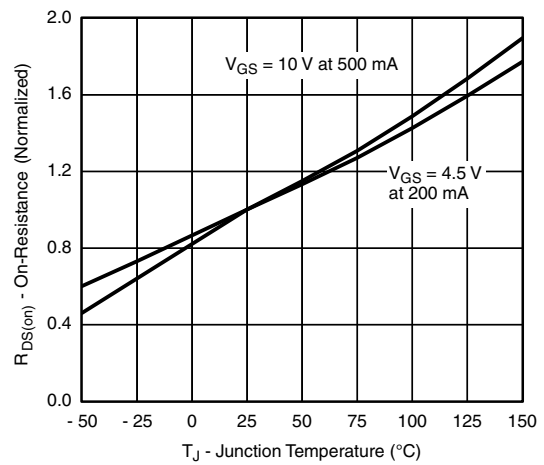
On-Resistance vs. Drain Current



Capacitance



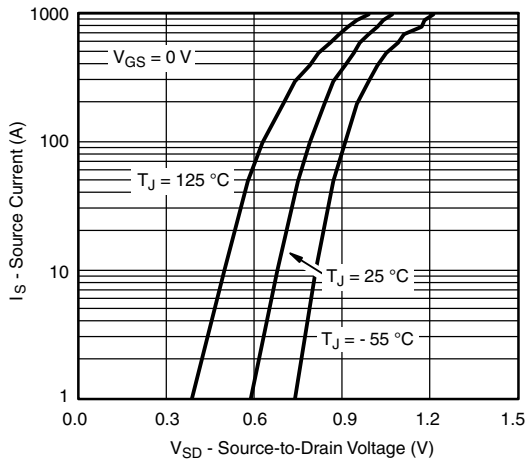
Gate Charge



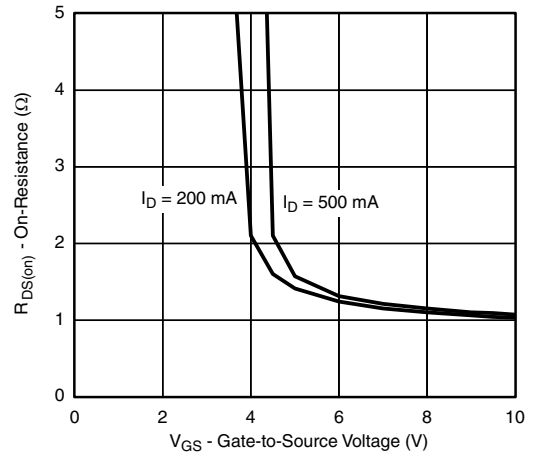
On-Resistance vs. Junction Temperature



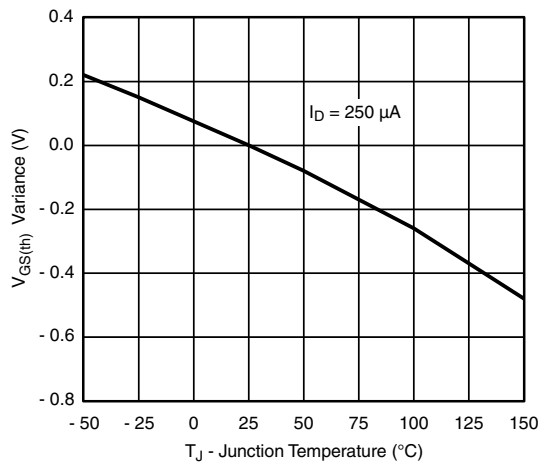
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



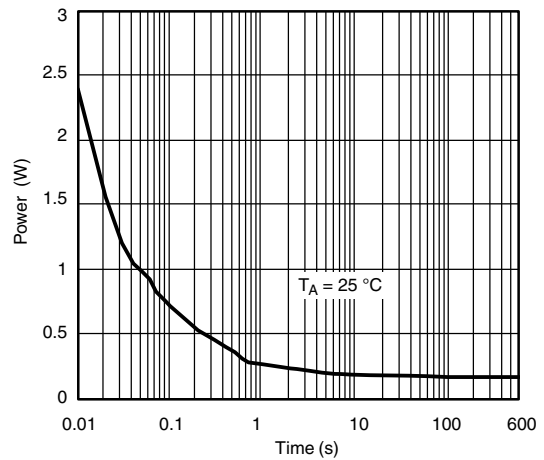
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-Source Voltage



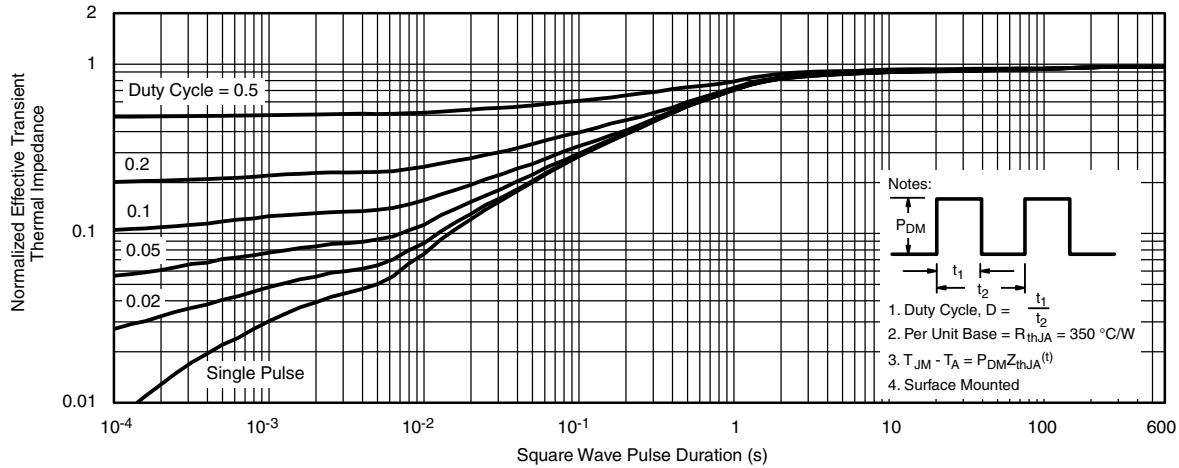
Threshold Voltage Variance Over Temperature



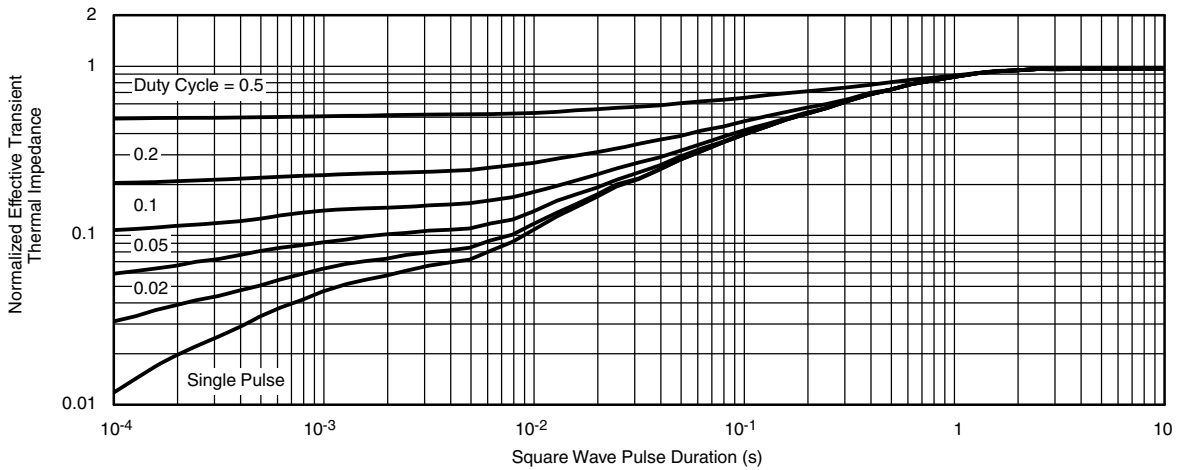
Single Pulse Power, Junction-to-Ambient



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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## SOT-23 (TO-236): 3-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A <sub>1</sub>	0.01	0.10	0.0004	0.004
A <sub>2</sub>	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E <sub>1</sub>	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e <sub>1</sub>	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L <sub>1</sub>	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°

ECN: S-03946-Rev. K, 09-Jul-01  
 DWG: 5479

## RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads  
Dimensions in Inches/(mm)

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